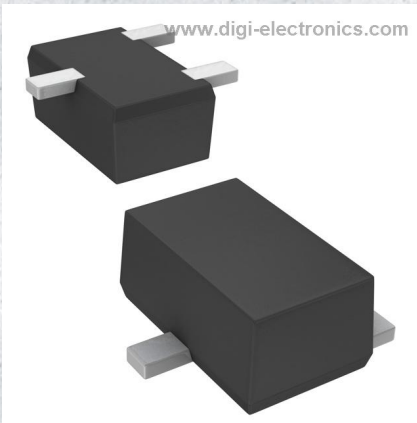


UNR515400L Datasheet



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	UNR515400L-DG
Manufacturer	Panasonic Electronic Components
Manufacturer Product Number	UNR515400L
Description	TRANS PREBIAS PNP 30V SMIN13
Detailed Description	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased 30 V 100 mA 80 MHz 150 mW Surface Mount SMin i3-G1



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

UNR515400L

Series:

-

Transistor Type:

PNP - Pre-Biased

Voltage - Collector Emitter Breakdown (Max):

30 V

Resistor - Emitter Base (R2):

47 kOhms

Vce Saturation (Max) @ Ib, Ic:

1.2V @ 330µA, 50mA

Frequency - Transition:

80 MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SMini3-G1

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100 mA

Resistor - Base (R1):

10 kOhms

DC Current Gain (hFE) (Min) @ Ic, Vce:

80 @ 5mA, 10V

Current - Collector Cutoff (Max):

500nA

Power - Max:

150 mW

Package / Case:

SC-70, SOT-323

Base Product Number:

UNR515

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.21.0095

ECCN:

EAR99

UNR5154 (UN5154)

Silicon PNP epitaxial planar type

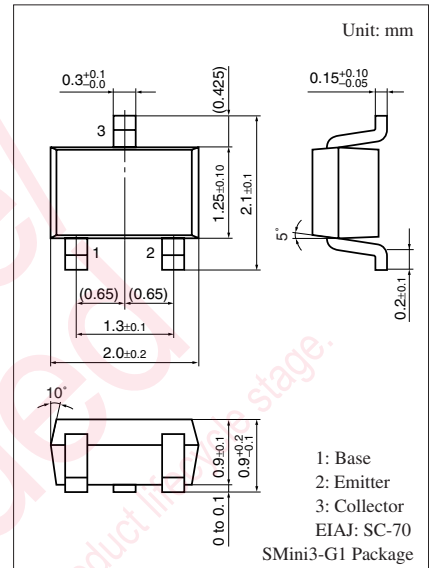
For digital circuits

■ Features

- High forward current transfer ratio h_{FE}
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts
- S-Mini type package, allowing automatic insertion through tape packing and magazine packing

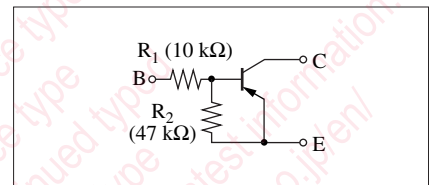
■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	-30	V
Collector-emitter voltage (Base open)	V_{CEO}	-30	V
Collector current	I_C	-100	mA
Total power dissipation	P_T	150	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$



Marking Symbol: EV

Internal Connection

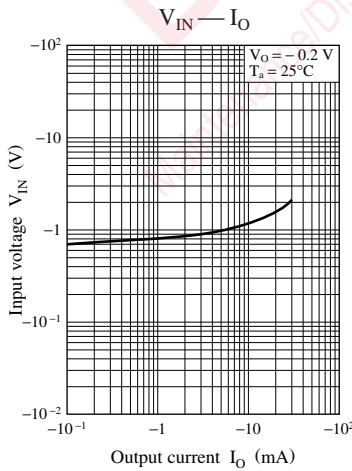
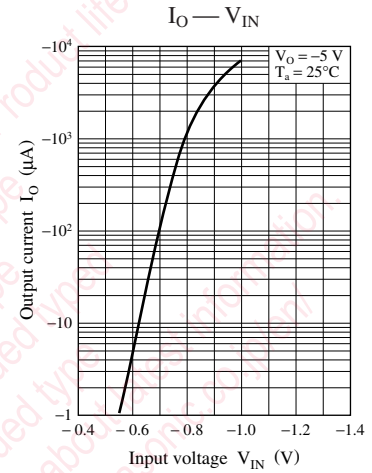
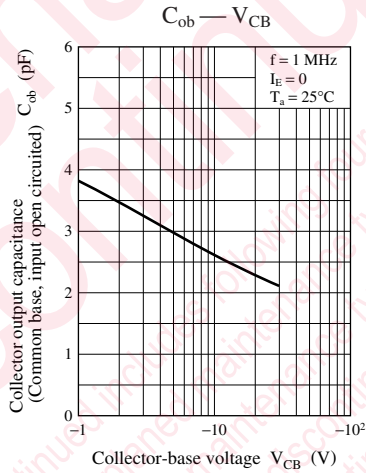
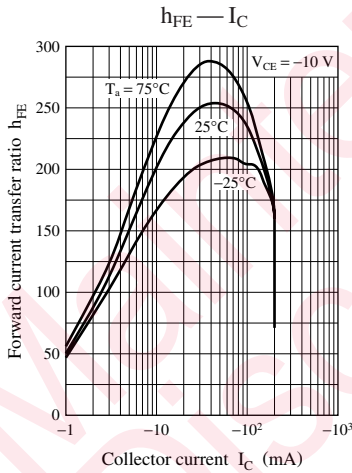
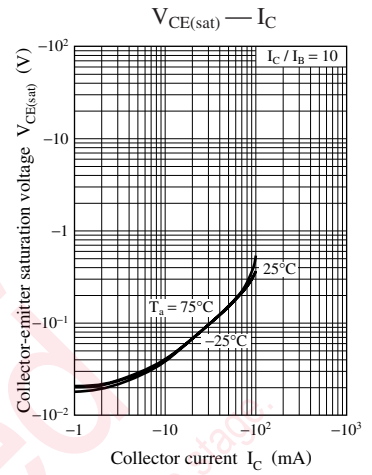
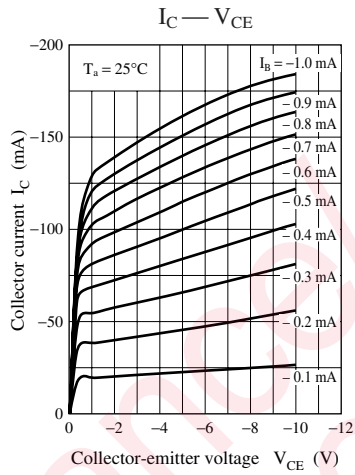
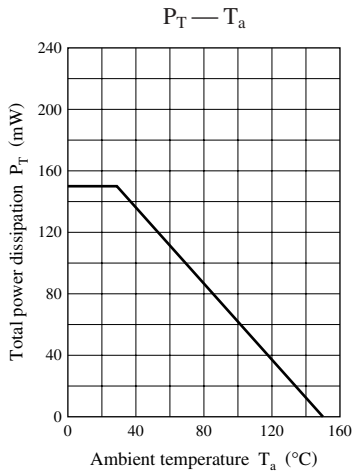


■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = -10 \mu\text{A}$, $I_E = 0$	-30			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = -2 \text{ mA}$, $I_B = 0$	-30			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -30 \text{ V}$, $I_E = 0$			-0.1	μA
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = -30 \text{ V}$, $I_B = 0$			-0.5	
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = -3 \text{ V}$, $I_C = 0$			-0.1	mA
Forward current transfer ratio	h_{FE}	$V_{CE} = -10 \text{ V}$, $I_C = -5 \text{ mA}$	80			—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -50 \text{ mA}$, $I_B = -0.33 \text{ mA}$		-0.5	-1.2	V
Output voltage high-level	V_{OH}	$V_{CC} = -5 \text{ V}$, $V_B = -0.5 \text{ V}$, $R_L = 1 \text{ k}\Omega$	-4.9			V
Output voltage low-level	V_{OL}	$V_{CC} = -5 \text{ V}$, $V_B = -2.5 \text{ V}$, $R_L = 1 \text{ k}\Omega$			-0.2	V
Transition frequency	f_T	$V_{CB} = -10 \text{ V}$, $I_E = 1 \text{ mA}$, $f = 200 \text{ MHz}$		80		MHz
Input resistance	R_1		-30%	10	+30%	$\text{k}\Omega$
Resistance ratio	R_1/R_2			0.213		—

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Note) The part number in the parenthesis shows conventional part number.



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